Diode Module

## **STARPOWER**

SEMICONDUCTOR

# **Rectifier Diode**

## **RD210HFS180C1S**

**Molding Type Module** 

1800V/210A 2 in one-package



### **General Description**

STARPOWER Rectifier Diode Power Module provides ultra low conduction loss. They are designed for the applications such as SMPS.

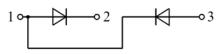
#### Features

- Low forward voltage drop
- Small temperature coefficient
- High Surge Capacity
- Low inductance
- Isolated Copper Baseplate Using DBC Technology



## **Typical Applications**

- Input bridge rectifier
- AC/DC motor control
- Power supply



Equivalent Circuit Schematic

Symbol	Description	RD210HFS180C1S	Units	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	1800	V	
V <sub>RSM</sub>	Non-repetitive Peak Reverse Voltage	1800	V	
I <sub>FAV</sub>	Average Forward Current $T_C=100^{\circ}C$	210	Α	
I <sub>FSM</sub>	Surge Forward Current $V_R=0V, t_p=10ms, T_j=45^{\circ}C$	3200	А	
	$V_{R}=0V, t_{p}=8.3 \text{ ms}, T_{j}=45 ^{\circ}\text{C}$	3450		
I <sup>2</sup> t	$I^2$ t-value $V_R=0V, t_p=10ms, T_j=45^{\circ}C$	51200	A <sup>2</sup> s	
	$V_{R}=0V, t_{p}=8.3 \text{ms}, T_{j}=45^{\circ}\text{C}$	49594		
P <sub>D</sub>	Maximum Power Dissipation @ T <sub>j</sub> =150°C	661	W	
Tj	Junction Temperature	-40 to +150	°C	
T <sub>STG</sub>	Storage Temperature Range	-40 to +125	°C	
V <sub>ISO</sub>	Isolation Voltage RMS,f=50Hz,t=1min	4000	V	
М	Terminal Connection Torque, Screw M6	2.5 to 5.0	N.m	
	Mounting Torque, Screw M6	3.0 to 5.0		

### Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

**Electrical Characteristics of Diode**  $T_C=25$  °C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Units
$V_{\rm F}$	Diode Forward	I <sub>F</sub> =300A	T <sub>j</sub> =25℃			1.18	v
	Voltage		T <sub>j</sub> =150℃			1.18	
I <sub>R</sub>	Diode Reverse	V <sub>R</sub> =V <sub>RRM</sub>	T <sub>j</sub> =25℃			0.10	mA
	Current		T <sub>j</sub> =150°C			3.50	

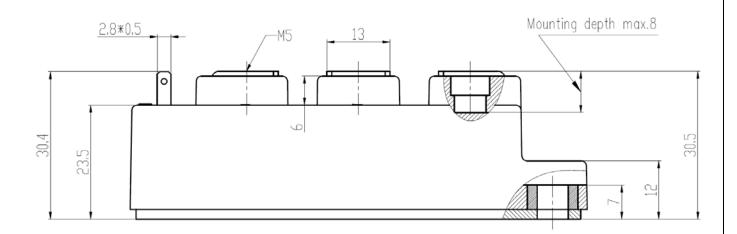
### **Thermal Characteristics**

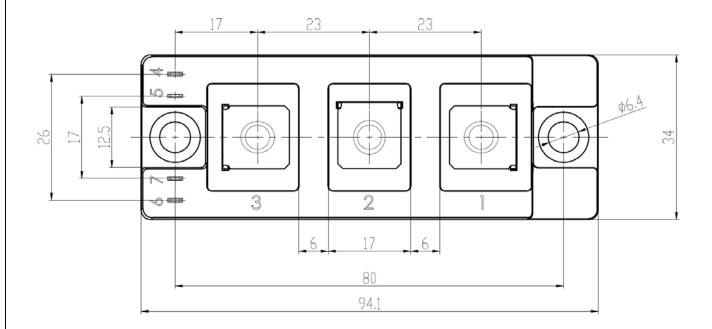
Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case (per Diode)		0.189	K/W
$R_{\theta CS}$	Case-to-Sink (Conductive grease applied)	0.05		K/W
Weight	Weight of Module	150		сŋ

#### Diode Module

### **Package Dimensions**

Dimensions in Millimeters





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